

# JIEJIE MICROELECTRONICS CO., LTD.

# JECR6006SCT EPI HYPERFAST RECOVERY RECTIFIER

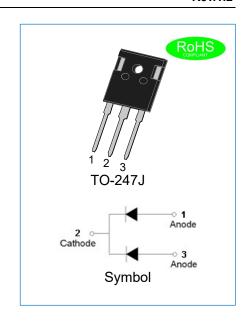
**Rev.1.2** 

#### **DESCRIPTION**

- Plastic package has underwriters laboratory flammability classification 94V-0
- ♦ Lead free in comply with EU RoHS 2011/65/EU directives
- ♦ Low reverse leakage current
- ♦ Hyperfast recovery time and soft recovery characteristics
- ♦ Low recovery loss
- Applications for PFC circuit (CCM), for white goods, for telecommunication device, etc.



- ♦ Case: TO-247J molded plastic over passivated junction
- ♦ Terminals: Solder plated, solderable per J-STD-002
- ♦ Weight:6 gram



## ABSOLUTE MAXIMUM RATING (Rating at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	JECR6006SCT	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	600	V
Maximum RMS voltage	V <sub>RMS</sub>	420	V
Maximum DC blocking voltage	$V_{DC}$	600	V
Average forward current at T <sub>mb</sub> ≤115°C	I <sub>F(AV)</sub>	60	Α
Peak forward surge current: 10ms single half sine-wave superimposed on rated load(per diode)	I <sub>FSM</sub>	270	А
Peak forward surge current: 8.3ms single half sine-wave superimposed on rated load(per diode)	I <sub>FSM</sub>	300	А
Junction temperature and storage temperature range	$T_{j},T_{stg}$	-55 to +150	$^{\circ}$



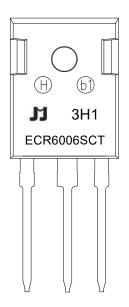
**ELECTRICAL CHARACTERISTICS**(Rating at 25°C ambient temperature unless otherwise specified.)

Parameter			Min.	Тур.	Max.	Unit
5 J II OL 20A	Tj=25℃		-	2.00	2.75	V
Forward voltage @I <sub>F</sub> =30A	Tj=150℃	V <sub>F</sub>	-	1.38	1.80	
DC reverse current	Tj=25℃		-	-	5	μА
at rated DC blocking voltage	Tj=150℃	l <sub>R</sub>	-	-	400	
	I <sub>F</sub> =1A,V <sub>R</sub> =30V,		-	18	22	ns
	di/dt=200A/μs,T <sub>j</sub> =25°C I <sub>F</sub> =30A,V <sub>R</sub> =200V,	- t <sub>rr</sub> -				
Doverse receiver time	di/dt=200A/µs,T <sub>j</sub> =25℃		-	35	-	
Reverse recovery time	I <sub>F</sub> =30A,V <sub>R</sub> =200V,		-	70	-	
	di/dt=200A/µs,T <sub>j</sub> =125℃					
	I <sub>F</sub> =30A,V <sub>R</sub> =400V,		-	29	-	
	di/dt=500A/µs,Tj=25℃					
	$I_F=30A, V_R=200V,$		-	3.5	-	A
Peak reverse recovery current	di/dt=200A/µs,Tj=25℃					
reak reverse recovery current	I <sub>F</sub> =30A,V <sub>R</sub> =200V,	I <sub>RM</sub>	-	7.6	-	
	di/dt=200A/µs,T <sub>j</sub> =125℃					
	I <sub>F</sub> =30A,V <sub>R</sub> =200V,		-	50	-	nC
December of charge	di/dt=200A/µs,T <sub>j</sub> =25℃	Q <sub>r</sub>				
Recovered charge	I <sub>F</sub> =30A,V <sub>R</sub> =200V,		-	280	-	
	di/dt=200A/µs,T <sub>j</sub> =125℃					

## THERMAL RESISTANCES

Symbol	Parameter	Min.	Тур.	Max.	Unit
R <sub>th(j-mb)</sub>	Thermal resistance from junction to mounting base	-	-	1	°C/W
R <sub>th(j-a)</sub>	Thermal resistance from junction to ambient free air	-	45	-	°C/W

#### **MARKING**



ECR	EPI Hyperfast Recovery Rectifier
60	I <sub>F(AV)</sub> =60A
06	V <sub>RRM</sub> :600V
S	Package:TO-247J
СТ	Common cathode

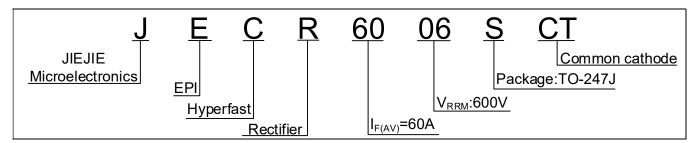
<u>x</u>H1: Month, 1/2/3~9/A/B/C

3**x**1:

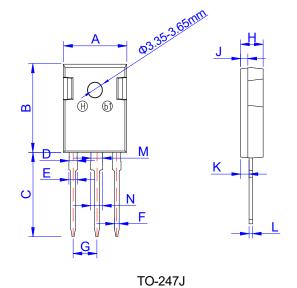
_						
2018	2019	2020	2021	2022	2023	2024
Н	I	J	K	L	М	Ν
2025	2026	2027	2028	2029	2030	
0	Р	Q	R	S	Т	

3Hx: Batch number

#### **ORDERING INFORMATION**



#### **PACKAGE MECHANICAL DATA**

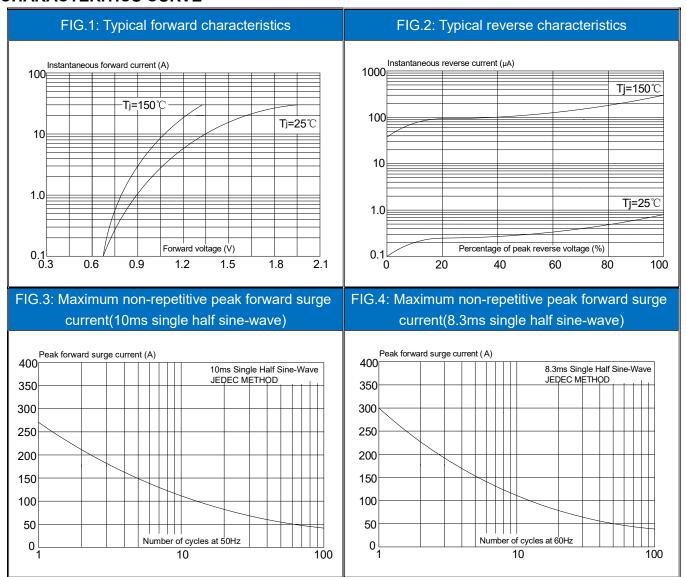


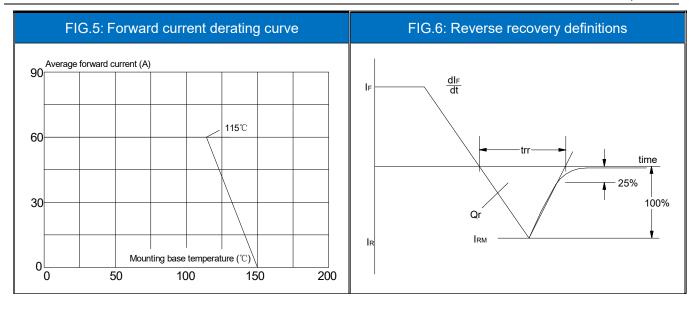
	Dimensions				Dime		
Ref.		Millimeters Inches		Millimeters			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	15.50	15.80	16.10	0.610	0.622	0.634	
В	20.80	21.00	21.20	0.819	0.827	0.835	
С	19.70	20.00	20.30	0.776	0.787	0.799	
D	1.80	2.00	2.20	0.071	0.079	0.087	
Е	1.90	2.10	2.30	0.075	0.083	0.091	
F	1.00	1.20	1.40	0.039	0.047	0.055	
G	5.25		5.65	0.207		0.222	
Н	4.80	5.00	5.20	0.189	0.197	0.205	
J	1.90	2.00	2.10	0.075	0.079	0.083	
K	2.20	2.35	2.50	0.087	0.093	0.098	
L	0.41	0.60	0.79	0.016	0.024	0.031	
М	2.80	3.00	3.20	0.110	0.118	0.126	
N	2.90	3.10	3.30	0.114	0.122	0.130	

#### **PACKAGE INFORMATION-TO-247J**

OUTLINE	UNIT WEIGHT	TUBE	PER CARTON
	(g/PCS) TYP	(PCS)	(PCS)
TUBE	6	30	2,250

#### **CHARACTERITICS CURVE**





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